20 MHz to 3.0 GHz Gain Block



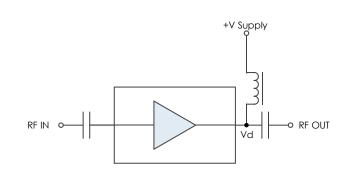
Description

AM1025B is a high dynamic range cascadable gain block covering the 20 MHz to 3.0 GHz frequency range. The device exhibits high P1dB, high second and third order intercept performance, and low noise figure while also providing excellent gain stability over the operating temperature range. With internal 50Ω matching and packaged in a 3mm QFN the AM1025B represents a compact total PCB footprint.

Features

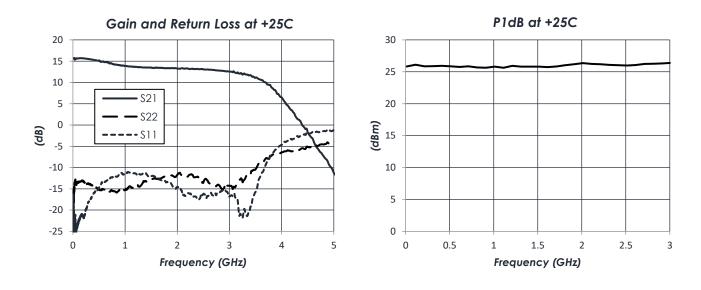
- 13.5 dB Gain
- +70 dBm OIP2
- +40 dBm OIP3
- +26 dBm P1dB
- +27 dBm PSat
- 3.8 dB Noise Figure
- +5.0V to +8.0V Supply Range
- 3mm QFN Package
- -40C to +85C Operation
- Unconditionally Stable





Characteristic Performance

(V Supply = +8.0V, Device Voltage [Vd] = +7.5V, Id = 156 mA)



20 MHz to 3.0 GHz Gain Block



Table of Contents

Description	1
Features	1
Functional Diagram	1
Characteristic Performance	1
Revision History	2
Pin Layout and Definitions	3
Specifications	4
Absolute Maximum Ratings	. 4
Handling Information	. 4
Recommended Operating Conditions	. 4

Thermal Information	4
DC Electrical Characteristics	5
RF Performance	5
Typical Performance	6
Typical Application	9
Typical Application Package Details	
	10
Package Details	10 11
Package Details Evaluation PC Board	10 11 11

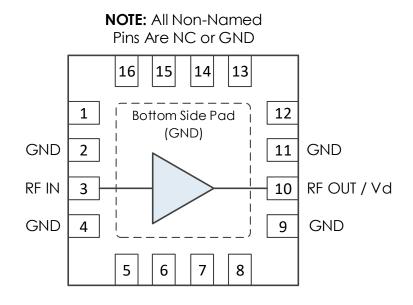
Revision History

Date	Revision Number	Notes
November 28, 2018	0	Preliminary Release.
November 30, 2018	0A	Recommended Ferrite Bead Changed, Extra Notes Added in Typical Application.
December 7, 2018	OB	Noise Figure vs VDD Added.
December 10, 2018	1	Initial Release.
January 21, 2019	2	Performance Plots Updated. Recommended Operating Conditions Modified.
May 13, 2019	3	Various Plots Updated.
June 6, 2019	3A	Component Compliance Information Updated



20 MHz to 3.0 GHz Gain Block

Pin Layout and Definitions



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground – Common
3	RF In	RF Input – 50 Ohms – DC Coupled, External DC Block Required
4	GND	Ground – Common
5 – 8	NC	Not Connected*
9	GND	Ground – Common
10	RF Out/ Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled,
		External DC Block Required
11	GND	Ground – Common
12-16	NC	Not Connected*
Bottom Pad	GND	Ground – Common

*Note: NC pins may be grounded or left open.

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Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+10.0 V
RF Input Power		+20 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.

Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+5.0 V	+8.0 V	+8.0 V
Device Voltage	+4.7 V	+7.5 V	+8.0 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+145 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance ($\Theta_{ m Jc}$)	51.6



20 MHz to 3.0 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage		+5.0 V	+8.0 V	+8.0 V
DC Device Voltage (Vd)		+4.7 V	+7.5 V	+8.0 V
DC Device Current	V Supply = +5.0 V		70 mA	
	V Supply = $+8.0$ V		156 mA	
Power Dissipated By IC	V Supply = +5.0 V		350 mW	
	V Supply = +8.0 V		1.17 W	

RF Performance

(T = 25 °C unless otherwise specified)

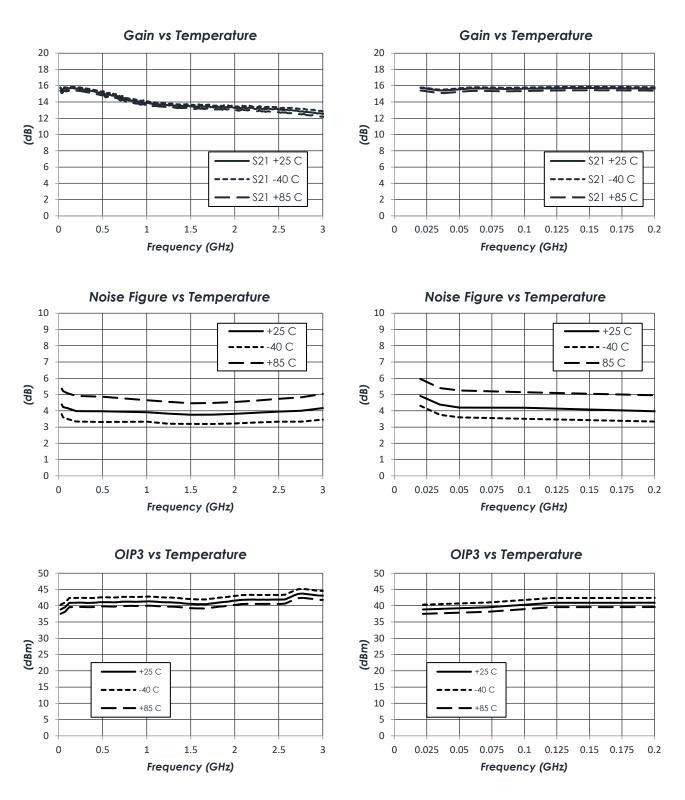
Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		20 MHz		3.0 GHz
Gain	V Supply = +8.0 V		13.5 dB	
Return Loss	V Supply = +8.0 V		14 dB	
Reverse Isolation	V Supply = +8.0 V		22 dB	
Output IP3	V Supply = +8.0 V		+40 dBm	
Output IP2	V Supply = +8.0 V		+70 dBm	
Output P1dB	V Supply = +8.0 V		+26 dBm	
Output Power Saturation	V Supply = +8.0 V		+27 dBm	
Noise Figure	V Supply = +8.0 V		3.8 dB	



20 MHz to 3.0 GHz Gain Block

Typical Performance

(V Supply = +8.0V, Device Voltage [Vd] = +7.5V, Id = 156 mA)

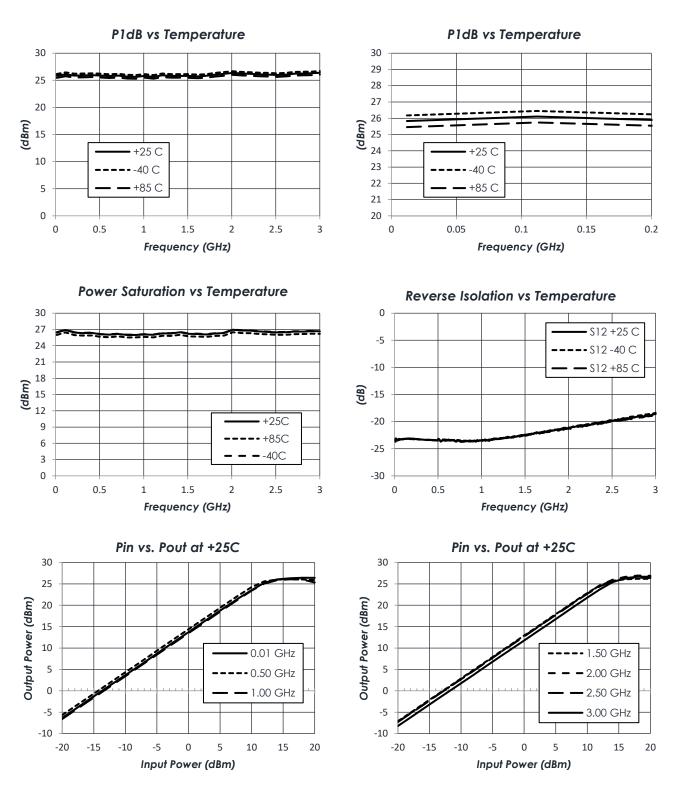




20 MHz to 3.0 GHz Gain Block

Typical Performance (continued)

(V Supply = +8.0V, Device Voltage [Vd] = +7.5V, Id = 156 mA)

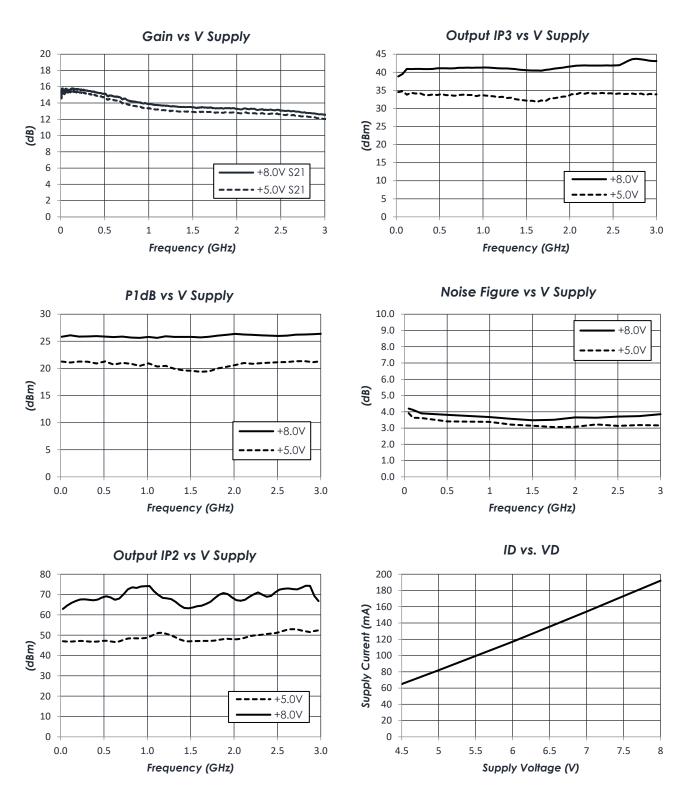


20 MHz to 3.0 GHz Gain Block



Typical Performance (continued)

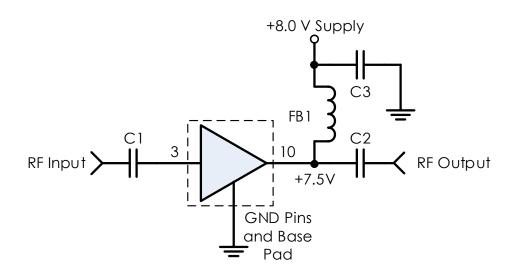
(T = 25°C Unless Otherwise Specified)





20 MHz to 3.0 GHz Gain Block

Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 µF	0402BB104KW160	Passives Plus
C3	0.1 µF	GRM155R71C104KA88	Murata
FB1	-	BLM15HG102SN1D	Murata

Notes:

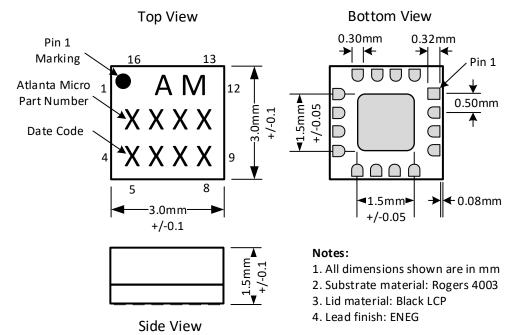
- 1. NC pins may be grounded or left open.
- 2. External DC blocking capacitors and RF choke are required.
 - a. RF blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance.
 - b. Select values for the frequency range of interest.
- 3. No input or output matching is required.

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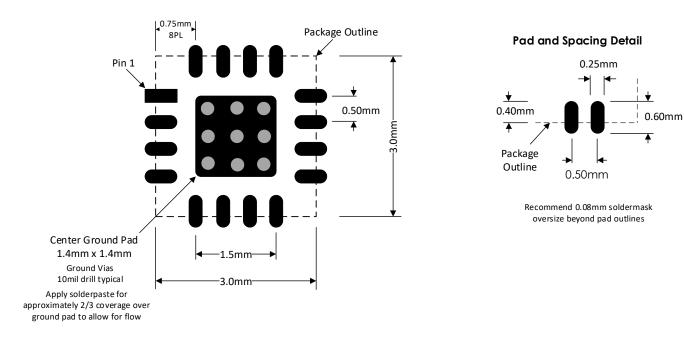


Package Details

Package Drawing



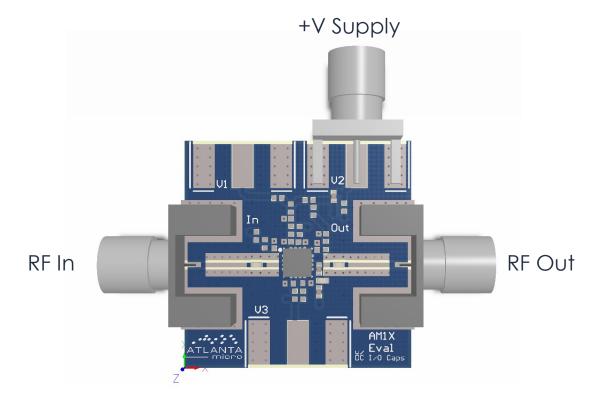
Recommended Footprint



ATLANTA —— micro

20 MHz to 3.0 GHz Gain Block

Evaluation PC Board



Related Parts

Part Number				Description
AM1016B	20 MHz	to	6 GHz	+3.3V Gain Block
AM1018B	20 MHz	to	6 GHz	+5.0V Gain Block
AM1018C	20 MHz	to	6 GHz	+5.0V Gain Block
AM1031C	20 MHz	to	8 GHz	+3.3V Gain Block
AM1063-1	DC	to	10 GHz	Gain Block
AM1063-2	DC	to	10 GHz	Miniature Gain Block
AM1064-1	DC	to	8 GHz	Gain Block
AM1064-2	DC	to	8 GHz	Miniature Gain Block



20 MHz to 3.0 GHz Gain Block

Component Compliance Information

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylheyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

REACH: Atlanta Micro, Inc. neither uses nor intentionally adds any of the substances considered to be a Substance of Very High Concern (SVHC) as defined by the EU Regulation (EC) No. 1907-2006 on Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH).

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Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.